

SI-3000KF Series Low Current Consumption, Low Dropout Voltage

■Features

- Compact full-mold package (equivalent to TO220)
- Output current: 1.0A
- Low dropout voltage: $V_{DIF} \leq 0.5V$ (at $I_o = 1.0A$)
- High ripple rejection: 75dB
- Low circuit current at output OFF: $I_q(\text{OFF}) \leq 1\mu A$
- Built-in overcurrent and thermal protection circuits

■Absolute Maximum Ratings

Parameter	Symbol	Ratings	Unit	Remarks
		SI-3010KF		
DC Input Voltage	V_{IN}	35 ¹	V	
Output Control Terminal Voltage	V_c	V_{IN}	V	
DC Output Current	I_o	1.0	A	
Power Dissipation	P_{D1}	16.6	W	With infinite heatsink
	P_{D2}	1.72	W	Without heatsink, stand-alone operation
Junction Temperature	T_j	-40 to +125	°C	
Storage Temperature	T_{STG}	-40 to +125	°C	
Operating Ambient Temperature	T_{OP}	-40 to +100	°C	
Thermal Resistance (Junction to Case)	θ_{j-c}	6.0	°C/W	
Thermal Resistance (Junction to Ambient Air)	θ_{j-a}	58	°C/W	Without heatsink, stand-alone operation

*1: A built-in input-overvoltage-protection circuit shuts down the output voltage at the Input Overvoltage Shutdown Voltage of the electrical characteristics.

■Applications

- Secondary stabilized power supply (local power supply)

■Recommended Operating Conditions

Parameter	Symbol	Ratings		Unit
		SI-3010KF		
Input Voltage Range	V_{IN}	2.4 ² to 27 ¹		V
Output Current Range	I_o	0 to 1.0 ¹		A
Output Voltage Variable Range	V_{OADJ}	1.1 to 16		V
Operating Ambient Temperature	T_{OP}	-30 to +85		°C
Operating Junction Temperature	T_j	-20 to +100		°C

*1: V_{IN} (max) and I_o (max) are restricted by the relationship P_d (max) = $(V_{IN} - V_o) \times I_o = 16.6W$.

*2: Refer to the Dropout Voltage parameter.

■Electrical Characteristics

Parameter	Symbol	Ratings			Unit	
		SI-3010KF				
		min.	typ.	max.		
Reference Voltage	V_{ADJ}	0.98	1.00	1.02	V	
	Conditions		$V_{IN}=7V, I_o=0.01A, V_c=2V, V_o=5A$			
Line Regulation	ΔV_{OLINE}			30	mV	
	Conditions		$V_{IN}=6$ to 15V, $I_o=0.01A, V_c=2V, V_o=5A$			
Load Regulation	ΔV_{OLoad}			75	mV	
	Conditions		$V_{IN}=7V, I_o=0$ to 1A, $V_c=2V, V_o=5A$			
Dropout Voltage	V_{DIF}			0.3	V	
	Conditions		$I_o=0.5A, V_c=2V, V_o=5V$			
	Conditions		$I_o=1.0A, V_c=2V, V_o=5V$	0.5		
Quiescent Circuit Current	I_q			600	μA	
Circuit Current at Output OFF	$I_q(\text{OFF})$			1	μA	
Temperature Coefficient of Output Voltage	$\Delta V_o/\Delta T_a$		± 0.5		$mV/^\circ C$	
Ripple Rejection	R_{REJ}		75		dB	
	Conditions		$V_{IN}=7V, I_o=0.1A, V_c=2V, f=100$ to 120Hz, $V_o=5V$			
Overcurrent Protection Starting Current ³	I_{S1}	1.1			A	
	Conditions		$V_{IN}=7V, V_c=2V$			
V_c	V_c, I_H	2			V	
	Conditions		$V_{IN}=7V$			
Terminal	V_c, I_L			0.8	V	
	Conditions		$V_{IN}=7V$			
Control Current (Output ON)	I_c, I_H			40	μA	
	Conditions		$V_{IN}=7V, V_c=2V$			
Control Current (Output OFF)	I_c, I_L	-5	0		μA	
	Conditions		$V_{IN}=7V, V_c=0V$			
Input Overvoltage Shutdown Voltage	V_{OVP}	33			V	
	Conditions		$I_o=0.01A$			

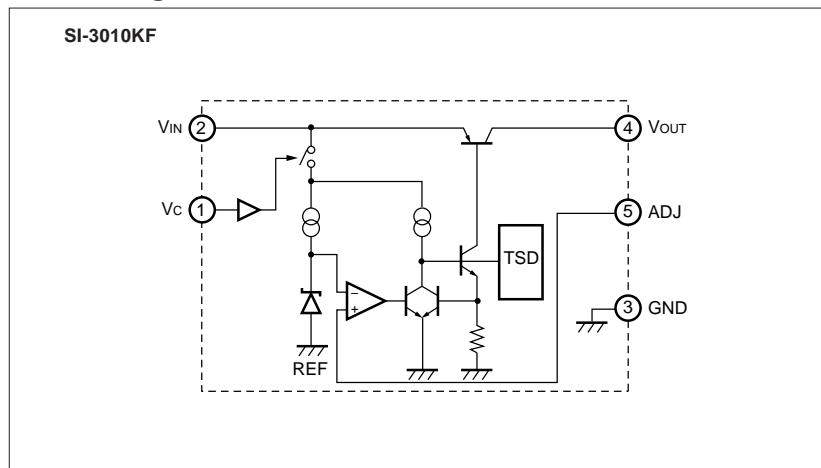
*3: I_{S1} is specified at the 5% drop point of output voltage V_o on the condition that V_{IN} = overcurrent protection starting current, $I_o = 10$ mA.

*4: Output is OFF when the output control terminal V_c is open. Each input level is equivalent to LS-TTL level. Therefore, the device can be driven directly by LS-TTLs.

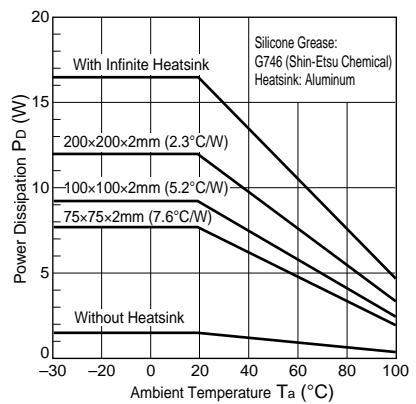
*5: SI-3000KFE cannot be used in the following applications because the built-in foldback-type overcurrent protection may cause errors during start-up stage.

(1) Constant current load (2) Positive and negative power supply (3) Series-connected power supply (4) V_o adjustment by raising ground voltage

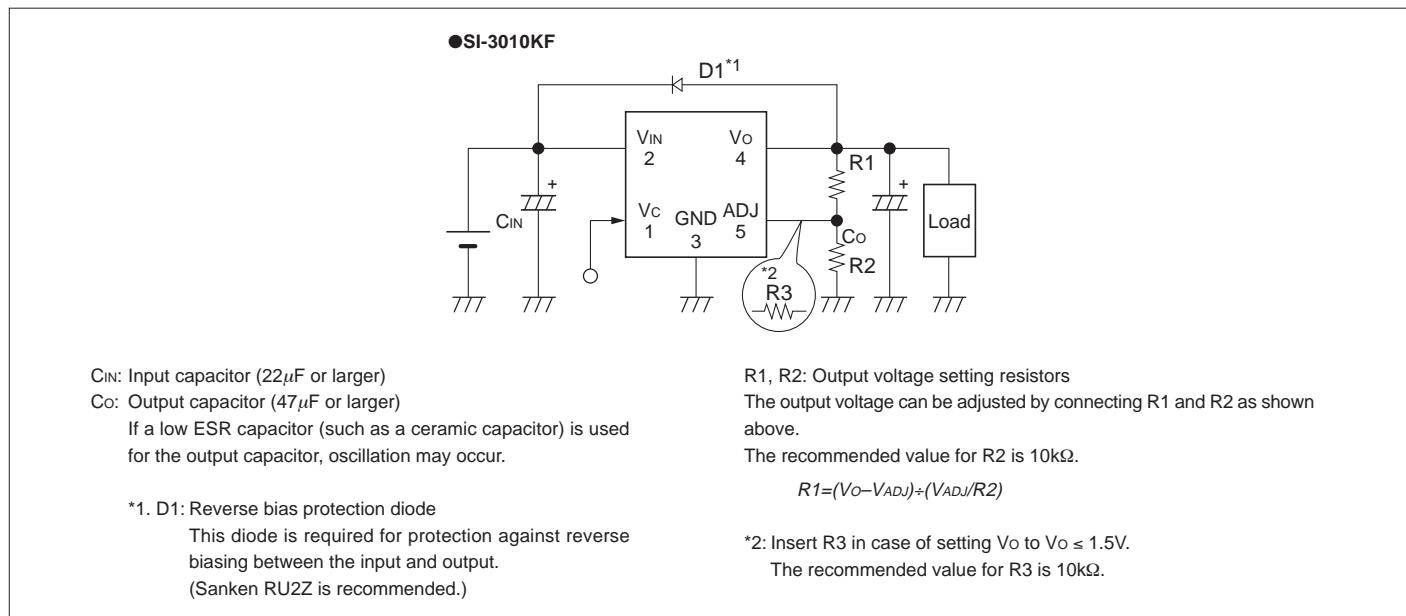
■Block Diagram



■Ta-PD Characteristics



■Typical Connection Diagram



■External Dimensions (TO220F-5)

(Unit : mm)

